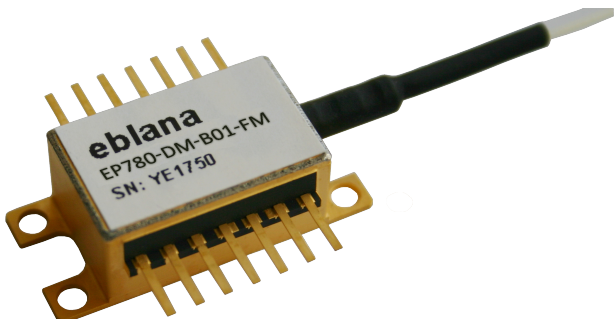


780nm DM LASER

EP780-DM-B

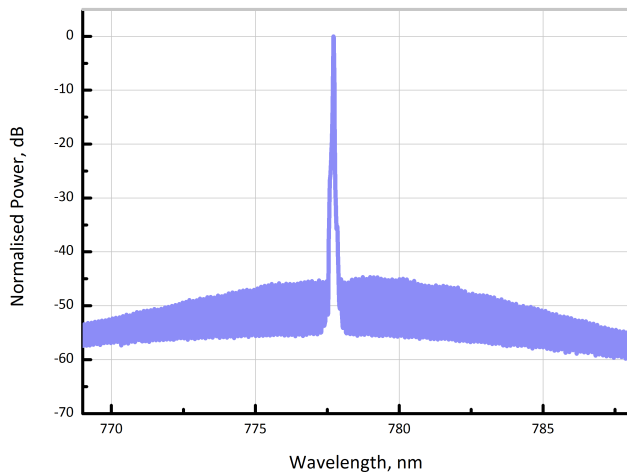


eblanaphotonics

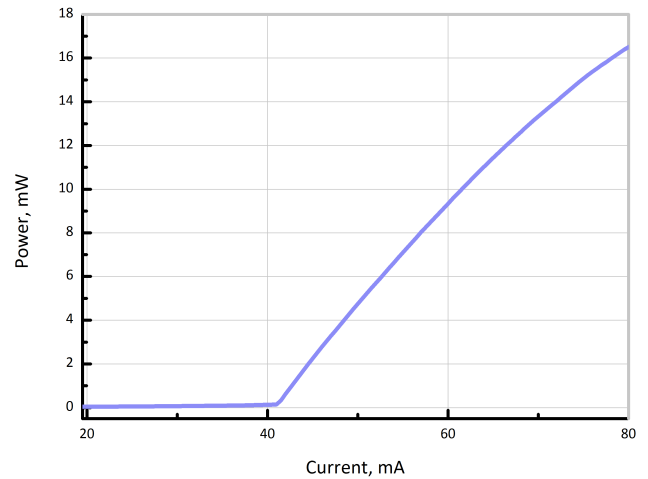


COHERENCE AND STABILITY

Eblana Photonics EP780-DM laser diode, available at a range of wavelengths from 778 - 784nm, is perfectly suited for use in Rb-based atomic clocks. Eblanas's patented Discrete-Mode (DM) technology is used to design a cost effective, highly coherent laser with mode-hop free tunability.



Optical Spectrum at 25°C



Output power as a function of bias current

ELECTRO-OPTICAL CHARACTERISTICS* ($T_{SUB} = 25^{\circ} C$)

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNIT |
|--------------------------------------|------------------|---------------|-----------|---------------|------------|
| Centre Wavelength Range | λ | 778 | 780 | 784 | nm |
| Wavelength specification | λ_{spec} | $\lambda - 1$ | λ | $\lambda + 1$ | nm |
| Side Mode Supression Ratio | SMSR | 30 | 40 | - | dB |
| Threshold Current | I_{th} | 30 | 40 | 50 | mA |
| Output Power in fiber (at I_{op}) | P_f | 10 | 12 | - | mW |
| Optical linewidth | Δf | - | - | 2 | MHz |
| Temperature Tuning Coefficient | T_{λ} | - | 0.1 | - | nm/°C |
| Current Tuning Coefficient | I_{λ} | 20 | 25 | - | pm/mA |
| Slope Efficiency | SE | 0.05 | 0.125 | - | mW/mA |
| Thermistor Resistance | R_T | 9.5 | 10 | 10.5 | k Ω |
| Thermistor Temp. Coefficient | C | - | -4.4 | - | %/°C |

*CW bias unless otherwise stated

©Eblana Photonics Series 780-DM-B Rev 2.0



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info@rpmclasers.com
O'Fallon, MO

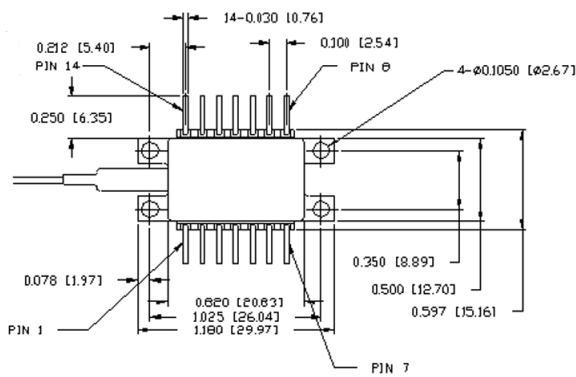
ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNIT |
|---------------------------|---------------|-----|-----|-----|------|
| Forward Current | I_f | - | 200 | 250 | mA |
| Forward Voltage | V_f | - | 3.5 | - | V |
| TEC Current | I_{TEC} | - | 0.5 | 1.2 | A |
| Reverse Voltage LD | V_r | - | - | 2.0 | V |
| Reverse Voltage PD | V_{rev} | - | - | 20 | V |
| Case Temperature* | T_{Case} | -20 | - | 65 | °C |
| Chip Submount Temperature | T_{Sub} | 0 | - | 50 | °C |
| Storage Temperature | $T_{storage}$ | -40 | - | 85 | °C |

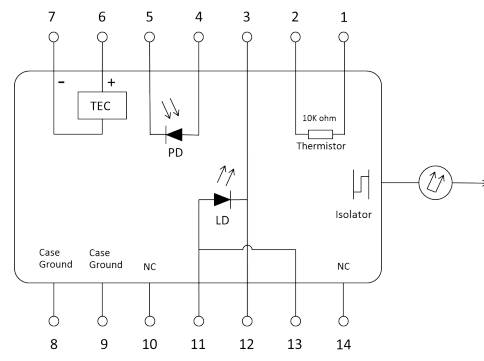
*For $T_{sub} < 25^{\circ}C$, Max Case Temperature should be derated to $T_{Case,Max} = T_{sub} + 40^{\circ}C$

PACKAGING

The EP780-DM-B product series is offered in a 14-pin Butterfly package - Please inquire for other packaging options. Standard package pinout is shown below, variations may be requested.



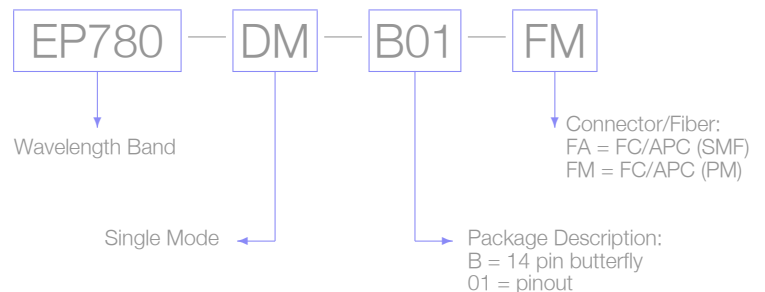
14-pin butterfly schematic



Standard "Pinout 01" option

HOW TO ORDER

Construct your part number using the following example and email your order to info@rpmclasers.com.



Laser Safety

This is a Class 3R Laser Product as defined by International Standard IEC 60825-1, Edition 2. Invisible Laser radiation is emitted from the end of the fiber or connector. Avoid direct eye exposure to the beam. Laser safety labels are not attached to the module due to space limitations but instead are affixed to the outside of the shipping carton.

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